捷多邦,专业PCB打样工厂,24小时加急出货

Philips Semiconductors

Thyristors

Product specification

BT152B series

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MAX. MAX. MAX. UNIT

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GENERAL DESCRIPTION

Glass passivated thyristors in a plastic envelope suitable for surface mounting, intended for use in applications requiring high bidirectional blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

PINNING - SOT404

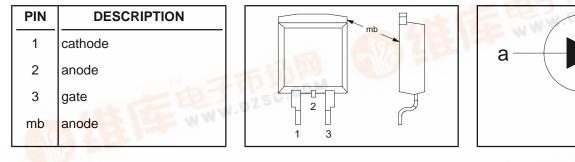
SYMBOL PARAMETER

QUICK REFERENCE DATA

OTHEOL		MIAA.	10000			
V _{DRM} , V _{RRM} I _{T(AV)} I _{T(RMS)} I _{TSM}	BT152B- Repetitive peak off-state voltages Average on-state current RMS on-state current Non-repetitive peak on-state current	400R 450 13 20 200	600R 650 13 20 200	800R 800 13 20 200	V A A A	

PIN CONFIGURATION

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

WWW.DZSC

SYMBOL	PARAMETER	CONDITIONS	MIN.	W W.	MAX.		UNIT
V _{DRM}	Repetitive peak off-state voltages			-400R 450 ¹	-600R 650 ¹	-800R 800	V
I _{T(AV)} I _{T(RMS)} I _{TSM}	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; $T_{mb} \le 103$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge	-		13 20		A A
NO		t = 10 ms t = 8.3 ms	-		200 220		A A
l²t dl _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after triggering		Ĩ	B	200 200		A ² s A/μs
I _{GM} V _{GM} V _{RGM}	Peak gate current Peak gate voltage Peak reverse gate voltage	HAR COIN	÷		5 5 5		A V V
$ \begin{array}{c} {}^{V} {}^{RGM} \\ {}^{P}{}^{GM} \\ {}^{P}{}^{G(AV)} \\ {}^{T}{}^{stg} \\ {}^{T}{}^{j} \end{array} $	Peak gate power Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- -40 -		20 0.5 150 125		ວໍວໍ≾&

Athough not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance		-	-	1.1	K/W
R _{th j-a}	junction to mounting base Thermal resistance junction to ambient	minimum footprint, FR4 board	-	55	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

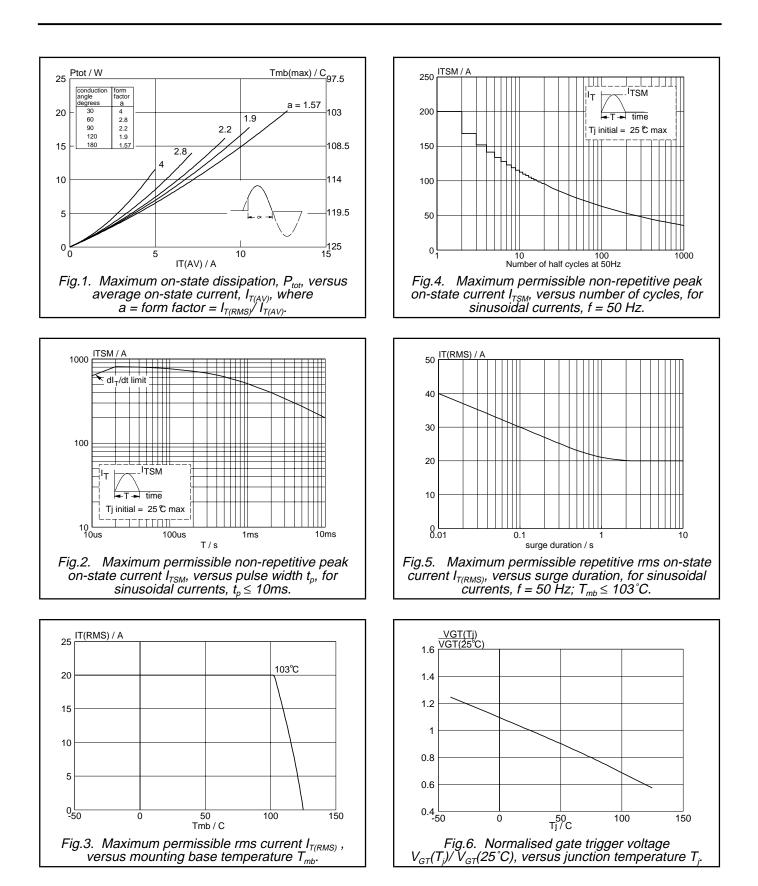
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	3	32	mA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	25	80	mA
	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	15	60	mA
İΫ _τ	On-state voltage	$I_{T} = 40 \text{ A}$	-	1.4	1.75	V
V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	0.6	1.5	V
		$V_{\rm D} = V_{\rm DRM(max)}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125 \ ^{\circ}\text{C}$	0.25	0.4	-	V
I _D , I _R	Off-state leakage current	$V_D = V_{DRM(max)}^{ORM(max)}; V_R = V_{RRM(max)}; T_j = 125 \ ^{\circ}C$	-	0.2	1.0	mA

DYNAMIC CHARACTERISTICS

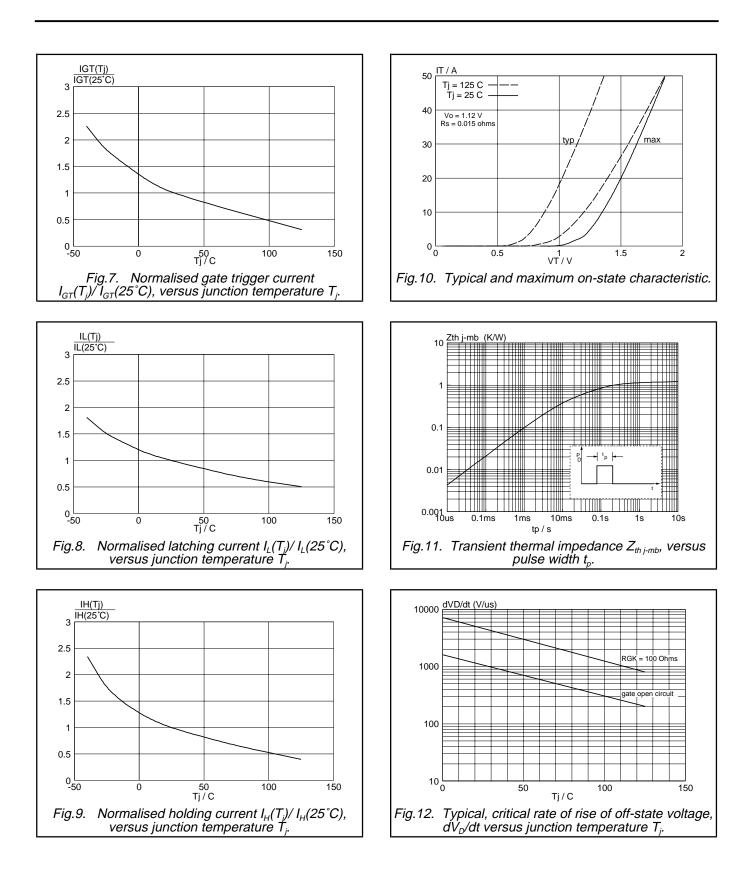
 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform gate open circuit	200	300	-	V/µs
t _{gt}	Gate controlled turn-on	$V_D = V_{DRM(max)}$; $I_G = 0.1$ Å; $dI_G/dt = 5$ Å/µs; $I_{TM} = 40$ Å	-	2	-	μs
t _q	Circuit commutated turn-off time		-	70	-	μs

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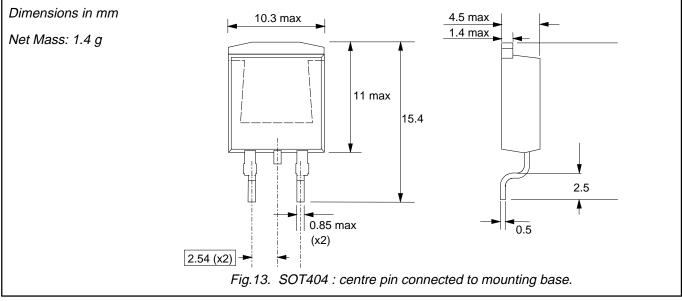


BT152B series



BT152B series

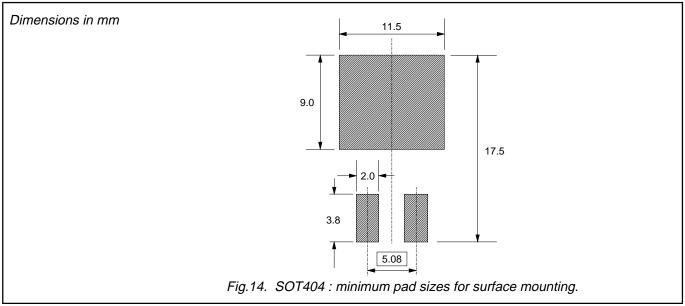
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status						
Objective specification This data sheet contains target or goal specifications for product development.						
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.					
Product specification	This data sheet contains final product specifications.					

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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